

Abstract Submitted  
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**Crystal structure and ferromagnetic phase transitions in  $\text{CeCu}_{1-x}\text{Ge}_{1+x}$  ( $0.0 \leq x \leq 0.3$ )**<sup>1</sup> W.H. LEE, S.Y. SHIH, H.H. SUNG, K.J. SYU, S.C. CHEN, National Chung Cheng University, W.H. LEE TEAM — As revealed in the powder x-ray diffraction and crystallographic data, the single phase sample in the series  $\text{CeCu}_{1-x}\text{Ge}_{1+x}$  ( $0.0 \leq x \leq 0.3$ ) crystallizes in the  $\text{AlB}_2$ -type structure with space group  $\text{P6}/\text{mmm}$ . The maximum ferromagnetic transition temperature  $T_c$  in  $\text{CeCu}_{1-x}\text{Ge}_{1+x}$ , as determined from the electrical- resistivity and magnetic susceptibility measurements, is 10.6 K for the compound  $\text{CeCu}_{0.8}\text{Ge}_{1.2}$ . The magnetic susceptibility for each sample in  $\text{CeCu}_{1-x}\text{Ge}_{1+x}$  ( $0.0 \leq x \leq 0.3$ ) follows Curie's behavior between 100 and 300 K with an effective moment  $2.6 \pm 0.1 \mu_B/\text{Ce}$  atom, a value close to that of  $\text{Ce}^{3+}$ . However, the observed saturation magnetic moment values ( $0.96 \sim 1.15 \mu_B$ ) at low temperatures for all these compounds are well less than the theoretically expected value  $2.14 \mu_B$  for the free  $\text{Ce}^{3+}$  ion tangling the entire six-fold  $J = 5/2$  multiplet. Subtracting the estimated phonon contribution from  $\text{LaCuGe}$ , the entropy associated with the magnetic structure of  $\text{CeCuGe}$  is found to meet the theoretical value of  $R \ln 2$ , which would be expected for a doublet ground state of  $\text{Ce}^{3+}$  ion in the compound  $\text{CeCuGe}$ . The reduced saturation moment in  $\text{CeCu}_{1-x}\text{Ge}_{1+x}$  is reasonably ascribed to partial lifting of the 4f-electron level degeneracy.

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